NSN 5961-00-777-3188

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-777-3188

Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length: 0.500 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Internal Configuration:	
Field effect	
Electrode Internally-electrically Connected To Case:	
Mounting Method:	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
30.0 drain to gate voltage and 30.0 drain to source voltage and -30.0 gate to source voltage	
Current Rating Per Characteristic:	
50.00 milliamperes gate current	
Power Rating Per Characteristic:	
1.8 watts total power dissipation	
Precious Material And Location:	
Terminal surface option gold	
Test Data Document:	
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in sp	pecifi
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on cer	rtain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-prf-19500/385 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	

A110a0

brochures, etc., that reflect specification type data in specification

NSN 5961-00-777-3188

Transistor - Page 2 of 2

Mil-std (military Standard):

Mil-prf-19500 spec.

